The demand must be filed directly with the competent International Preliminary Examining Authority or, if two or more Authorities are competent, with the one chosen by the applicant. The full name or two-letter code of that Authority may be indicated by the applicant on the line below:

IPEA/US

PCT

CHAPTER II

DEMAND

under Article 31 of the Patent Cooperation Treaty:

The undersigned requests that the international application specified below be the subject of international preliminary examination according to the Patent Cooperation Treaty.

For	r International Preliminar	y Examining Authorit	y use only	
Identification of IPEA		Date of receipt of D	EMANU	
Box No. I IDENTIFICATION OF T	HE INTERNATIONAL	APPLICATION	Applicant's or agent's file reference 30794108WO01	
International application No. PCT/US03/39211	International filing date (day/month/year) 09 December 2003 (09.12.2003)		(Earliest) Priority date (day/month/year)	
Title of invention HIGHLY EFFICIENT GALLIUM NI ROUGHENING	TRIDE BASED LIGH	IT EMITTING DIO	DES VIA SURFACE	
Box No. II APPLICANT(S)				
Name and address: (Family name followed by The address must include p	given name; for a legal entity, ostal code and name of country	full official designation.	Telephone No.	
THE REGENTS OF THE UN 1111 Franklin Street, 12th Fl		ALIFORNIA	Facsimile No.	
Oakland, California 94607	001		Teleprinter No.	
United States of America			Applicant's registration No. with the Office	
State (that is, country) of nationality:		State (that is, count	ry) of residence:	
Name and address: (Family name followed by FUJII, Tetsuo 7240 Davenport Road, #104 Goleta, California 93117 United States of America		full official designation. The	e address must include postal code and name of country.)	
State (that is, country) of nationality:	······································	State (that is, countr	y) of residence:	
	given name; for a legal entity,	full official designation. The	e address must include postal code and name of country.)	
GAO, Yan 705 Bolton Walk, #102 Goleta, California 93117 United States of America				
State (that is, country) of nationality:		State (that is, country,) of residence:	
Further applicants are indicated on	a continuation sheet.			

Sheet No. ..2

International application No. PCT/US03/39211

Continuation of Box No. II APPLICANT(S)		
If none of the following sub-boxes is used, this sheet should not be included in the demand.		
Name and address: (Family name followed by given name: for a legal entity, for HU, Evelyn L. 1160 North Fairview Avenue Goleta, California 93117 United States of America	ull official designation. The address must include postal code and name of country.)	
State (that is, country) of nationality:	State (that is, country) of residence:	
Name and address: (Family name followed by given name: for a legal entity, for a legal	ull official designation. The address must include postal code and name of	
State (that is, country) of nationality: JP	State (that is, country) of residence: US	
Name and address: (Family name followed by given name; for a legal entity, fu	·	
State (that is, country) of nationality:	State (that is, country) of residence:	
Name and address: (Family name followed by given name; for a legal entity, fu	ll official designation. The address must include postal code and name of country.)	
State (that is, country) of nationality:	State (that is, country) of residence:	
Further applicants are indicated on another continuation shee	et.	

Sheet No. . . 3

International application No. PCT/US03/39211

Box No. III AGENT OR COMMON REPRESENTATIVE; OR ADDRESS FOR CORRESPONDENCE			
The following person is agent common representative			
and 🗶 has been appointed earlier and represents the applicant(s) also for international preliminary examination.			
is hereby appointed and any earlier appointment of (an) agent(s)/common represe	entative is hereby revoked.		
is hereby appointed, specifically for the procedure before the International Prelim the agent(s)/common representative appointed earlier.	ninary Examining Authority, in addition to		
Name and address: (Family name followed by given name; for a legal entity, full official designation. The address must include postal code and name of country.)	Telephone No.		
	310-641-8797		
GATES, George H. GATES & COOPER LLP	Facsimile No. 310-641-8798		
6701 Center Drive West, Suite 1050			
Los Angeles, California 90045	Teleprinter No.		
United States of America	Agent's registration No. with the Office		
Address for correspondence: Mark this check-box where no agent or common to	representative is has been appointed and the		
space above is used instead to indicate a special address to which correspondence	e should be sent.		
Box No. IV BASIS FOR INTERNATIONAL PRELIMINARY EXAMINATION			
Statement concerning amendments:*			
1. The applicant wishes the international preliminary examination to start on the basis o	f:		
the international application as originally filed			
the description as originally filed			
as amended under Article 34			
the claims as originally filed			
as amended under Article 19 (together with any accompanying	ng statement)		
as amended under Article 34			
the drawings as originally filed			
as amended under Article 34			
2. The applicant wishes any amendment to the claims under Article 19 to be considered.	lered as reversed.		
3. Where the IPEA wishes to start the international preliminary examination at the accordance with Rule 69.1(b), the applicant requests the IPEA to postpone	he same time as the international search in the start of the international preliminary		
examination until the expiration of the applicable time limit under Rule 69.1(d). The applicant expressly wishes the international preliminary examination to			
applicable time limit under Rule 54bis.1(a).			
Where no check-box is marked, international preliminary examination will start on as originally filed or, where a copy of amendments to the claims under Article 19 and/or under Article 34 are received by the International Preliminary Examining Authority before or the international preliminary examination report, as so amended.	amendments of the international application		
Language for the purposes of international preliminary examination: .English			
which is the language in which the international application was filed.			
which is the language of a translation furnished for the purposes of internation	onal search.		
which is the language of publication of the international application.			
which is the language of the translation (to be) furnished for the purposes of	international preliminary examination.		
Box No. V ELECTION OF STATES			
The filing of this demand constitutes the election of all Contracting States which are desi PCT.	gnated and are bound by Chapter II of the		

		Sheet N	io 4			PCT/US03/	
Box No.	VI CHECK LIST						<u></u>
	emand is accompanied by the following el to. IV, for the purposes of international pro-			erred t	to in		onal Preliminary uthority use only not received
1. tra	inslation of international application	:		sh	eets		
2. an	nendments under Article 34	:		sh	eets		·
	py (or, where required, translation) of nendments under Article 19	:		3 sh	eets		
	py (or, where required, translation) of tement under Article 19	:		sh	eets		
5. let	ter	:	;	2 sh	eets		
6. otl	ner (specify)	:		sh	eets		
The dem	and is also accompanied by the item(s) m	arked below:			.		
1. 🗶	fee calculation sheet		5. 🔲	staten	nent explai	ning lack of signat	ure
2.	original separate power of attorney		6.	seque	nce listing	in electronic form	
3. 🔲	original general power of attorney		7.		in electron nce listing	nic form related to	a
4. 🔲	copy of general power of attorney; reference number, if any:		8. 🔀	other	(specify):	Transmittal she	eet (in duplicate);
	VII SIGNATURE OF APPLICANT, th signature, indicate the name of the person signi				PRESENT	ATIVE	
By:	eorge H. Gates		Date	e: 23	May 20	005	
	For Internati	onal Preliminary E	Examini	ng Aut	thority use	only -	7
1. Date	of actual receipt of DEMAND:	,			y		
	sted date of receipt of demand due ORRECTIONS under Rule 60.1(b):			<u>-</u>			
3.	The date of receipt of the demand is expiration of 19 months from the prio item 4 or 5, below, does not apply.		6.	⊢ ex	piration of		nand is AFTER the rRule 54 <i>bis</i> . I(a) and ply.
4.	The applicant has been informed. The date of receipt of the demand is WIT	HIN the time	7.	ا الـ	he date of re mit under F ule 80.5.	eceipt of the demand Rule 54 <i>bis</i> .1(a) as 6	d is WITHIN the time extended by virtue of
5.	limit of 19 months from the priority date by virtue of Rule 80.5. Although the date of receipt of the dema expiration of 19 months from the prio delay in arrival is EXCUSED pursuant	nd is after the	8.	ex اــ	piration of	the time limit unde	the demand is after the er Rule 54 <i>bis</i> .1(a), the oursuant to Rule 82.
		For International	Bureau	use on	nly		
Demand	received from IPEA on:						

PCT

FEE CALCULATION SHEET

Annex to the Demand

		For International Preliminary Examining Authority use onl	v —
	national cation No. PCT/US03/39211	To memanda remaining reasons as one	,
	licant's or agent's eference 30794108WO01	Date stamp of the IPEA	
Ann	icant		
	E REGENTS OF THE UNIVERSITY OF C	CALIFORNIA et al.	
CA	LCULATION OF PRESCRIBED FEES		
1.	Preliminary examination fee	600. P	—
2.	Handling fee (Applicants from certain States are entitled to a reduction of 75% of the handling fee. Where the applicant is (or all applicants are) so entitled, the amount to be entered at H is 25% of the handling fee.)	173. H	
3.	Total of prescribed fees Add the amounts entered at P and H and enter total in the TOTAL box	773.	
мо	DE OF PAYMENT		
X	authorization to charge deposit cash account with the IPEA (see below) cheque revenue st	stamps	
	postal money order coupons		
	bank draft other (spec	ecify):	
	HORIZATION TO CHARGE (OR CREDIT) DEPOSIT A mode of payment may not be available at all IPEAs)	ACCOUNT IPEA/ US	
X	Authorization to charge the total fees indicated above.	Deposit Account No.: 50-0494	
X	(This check-box may be marked only if the conditions for	Date: 23 May 2005	
	deposit accounts of the IPEA so permit) Authorization to charge any deficiency or credit any overpayment in the	Name: George H. Gates	
	total fees indicated above.	Signature:	

Form PCT/IPEA/401 (Annex) (April 2005)

See Notes to the fee calculation sheet

In re application of: THE REGENTS OF THE UNIVERSITY OF CALIFORNIA

International Application No.: PCT/US03/39211 International Filing Date: 9 December 2003

Agent's Reference: 30794108WO01

Title: HIGHLY EFFICIENT GALLIUM NITRIDE BASED LIGHT EMITTING

DIODES VIA SURFACE ROUGHENING

AMENDMENT UNDER ARTICLE 19 BEFORE THE INTERNATIONAL BUREAU OF WIPO

VIA FACSIMILE CONFIRMATION VIA FEDERAL EXPRESS

The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20 SWITZERLAND

Dear Sir or Madam:

In response to the Search Report dated 26 May 2004, please amend the above-identified application as indicated below:

IN THE CLAIMS

It is requested that the claims of the above-referenced application be amended as provided on replacement pages 16-18 attached herewith. No new matter has been introduced by these amendments. The claims correspond to the current PCT claims as follows:

Claims	Status
1-2	Amended
3-7	Unchanged
8	Amended
9-14	Unchanged
15-16	Amended
17-18	Unchanged

RESPONSE TO

SEARCH REPORT

REMARKS

In view of the above amendments, it is submitted that the claims are in a condition for a positive examination report. If this is not the case, the Examiner is encouraged to contact the Applicant's representative since a positive report is requested.

Please direct any inquiry to the below-signed attorney.

Respectfully submitted,

GATES & COOPER LLP 6701 Center Drive West, Suite 1050 Los Angeles, California 90045 United States of America (310) 641-8797

ATTORNEYS FOR APPLICANT(S)

Date: 22 July 2004

RESPONSE TO SEARCH REPORT

WHAT IS CLAIMED IS:

1. A gallium nitride (GaN) based light emitting diode (LED), wherein light is extracted through a nitrogen face (N-face) of the LED and a surface of the N-face is roughened.

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2. The GaN LED of claim 1, wherein the surface of the N-face is roughened into one or more cones.

The GaN LED of claim 1, wherein the roughened surface reduces light reflections occurring repeatedly inside the LED, and thus extracts more light out of the LED.

4. The GaN LED of claim 1, wherein the surface of the N-face is roughened by an anisotropic etching.

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- 5. The GaN LED of claim 4, wherein the anisotropic etching is a dry etching.
- 6. The GaN LED of claim 4, wherein the anisotropic etching is a photo-20 enhanced chemical (PEC) etching.
 - 7. The GaN LED of claim 1, wherein the N-face is an n-type layer of the GaN LED.
- 25 8. The GaN LED of claim 1, wherein the N-face is prepared by a laser lift off (LLO) technique.
 - 9. The GaN LED of claim 1, wherein the LED is grown on a c-plane GaN wafer and a gallium face (Ga-face) is a p-type layer.

- 10. The GaN LED of claim 1, wherein the LED is comprised of an n-type electrode, n-type layer, active region, p-type layer and p-type electrode.
- 5 11. The GaN LED of claim 10, wherein the n-type layer, active region and p-type layer are each comprised of a (B, Al, Ga, In)N alloy.
 - 12. The GaN LED of claim 10, wherein the p-type electrode has a property of high reflection to decrease light absorption and to increase light reflection toward the surface of the n-type layer.
 - 13. The GaN LED of claim 10, wherein the LED includes a current-blocking layer aligned under the n-type electrode to keep the current from concentrating below the n-type electrode, so that absorption of light emission under the n-type electrode can be avoided and extraction efficiency can be increased.
 - 14. The GaN LED of claim 10, wherein the LED includes a current-confining frame made of an insulator to restrain leakage current through the sidewalls of the LED without significantly decreasing an emitting area.
 - 15. The GaN LED of claim 2, wherein the roughened surface is comprised of a plurality of hexagonal shaped cones that have an angle equal to or smaller than:

$$2\sin^{-1}(n_{air}/n_s)\approx 47.2^{\circ}$$

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for GaN, where n_{air} is a refractive index of air and n_s is a refractive index of GaN.

16. The GaN LED of claim 2, wherein the roughened surface is comprised of a plurality of hexagonal shaped cones that have an angle equal to or smaller than:

$$2\sin^{-1}(n_{enc}/n_s)$$

10

- for epoxy, where n_{enc} is a refractive index of epoxy and n_s is a refractive index of GaN.
 - 17. A method of creating a gallium nitride (GaN) based light emitting diode (LED), wherein light is extracted through a nitrogen face (N-face) of the LED, comprising:

roughening a surface of the N-face into one or more cones.

18. A light emitting diode (LED) comprised of an n-type electrode, n-type layer, active region, p-type layer and p-type electrode, wherein a surface of the n-type layer is roughened by an anisotropic etching into one or more cones and light is extracted through the roughened surface of the n-type layer.